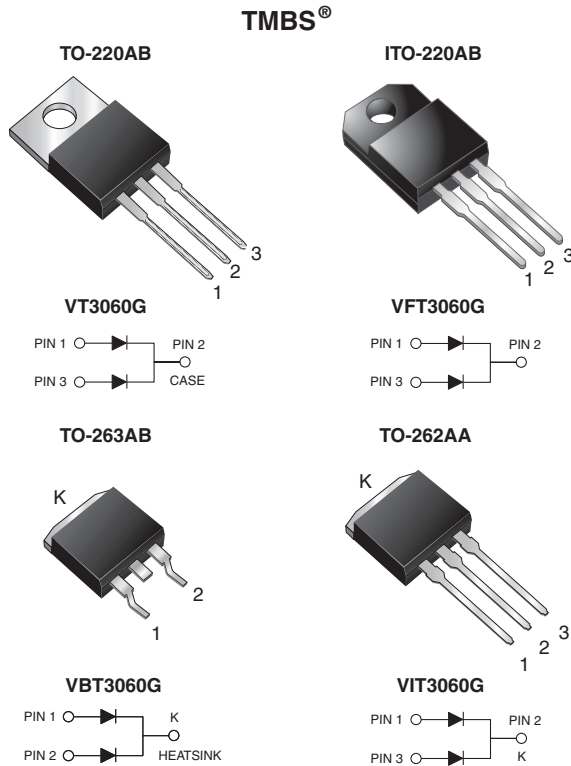


# Dual High Voltage Trench MOS Barrier Schottky Rectifier

 Ultra Low  $V_F = 0.40\text{ V}$  at  $I_F = 5\text{ A}$ 


## FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Not recommended for PCB bottom side wave mounting
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT

## TYPICAL APPLICATIONS

For use in high frequency inverters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

## MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs max.

## PRIMARY CHARACTERISTICS

|                              |   |
|------------------------------|---|
| $I_{F(AV)}$                  | 2 x 15 A                                |
| $V_{RRM}$                    | 60 V                                    |
| $I_{FSM}$                    | 150 A                                   |
| $V_F$ at $I_F = 15\text{ A}$ | 0.61 V                                  |
| $T_J$ max.                   | 150 °C                                  |
| Package                      | TO-220AB, ITO-220AB, TO-263AB, TO-262AA |
| Diode variations             | Common cathode                          |

## MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)

| PARAMETER   | SYMBOL         | VT3060G       | VFT3060G | VBT3060G | VIT3060G | UNIT |
|---|----------------|---------------|----------|----------|----------|------|
| Max. repetitive peak reverse voltage  | $V_{RRM}$      | 60            |          |          |          | V    |
| Max. average forward rectified current (fig. 1)   | $I_{F(AV)}$    | per device    | 30       |          |          | A    |
|   |                | per diode     | 15       |          |          |      |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load                                      | $I_{FSM}$      | 150           |          |          |          | A    |
| Non-repetitive avalanche energy at $T_J = 25\text{ °C}$ , $L = 60\text{ mH}$ per diode                                  | $E_{AS}$       | 120           |          |          |          | mJ   |
| Peak repetitive reverse current at $t_p = 2\text{ }\mu\text{s}$ , 1 kHz, $T_J = 38\text{ °C} \pm 2\text{ °C}$ per diode | $I_{RRM}$      | 1.0           |          |          |          | A    |
| Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1\text{ min}$   | $V_{AC}$       | 1500          |          |          |          | V    |
| Operating junction and storage temperature range  | $T_J, T_{STG}$ | - 55 to + 150 |          |          |          | °C   |



| ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                         |   |                 |           |           |          |
|--|-------------------------|---|-----------------|-----------|-----------|----------|
| PARAMETER  | TEST CONDITIONS         |   | SYMBOL          | TYP.      | MAX.      | UNIT     |
| Breakdown voltage  | I <sub>R</sub> = 1.0 mA | T <sub>A</sub> = 25 °C                            | V <sub>BR</sub> | 60 (min.) | -         | V        |
| Instantaneous forward voltage per diode <sup>(1)</sup>                     | I <sub>F</sub> = 5 A    | T <sub>A</sub> = 25 °C                            | V <sub>F</sub>  | 0.49      | -         | V        |
|  | I <sub>F</sub> = 7.5 A  |   |                 | 0.53      | -         |          |
|  | I <sub>F</sub> = 15 A   |   |                 | 0.65      | 0.73      |          |
|  | I <sub>F</sub> = 5 A    | T <sub>A</sub> = 125 °C                           |                 | 0.40      | -         |          |
|  | I <sub>F</sub> = 7.5 A  |   |                 | 0.46      | -         |          |
|  | I <sub>F</sub> = 15 A   |   |                 | 0.61      | 0.69      |          |
| Reverse current per diode <sup>(2)</sup>                                   | V <sub>R</sub> = 60 V   | T <sub>A</sub> = 25 °C<br>T <sub>A</sub> = 125 °C | I <sub>R</sub>  | -<br>14   | 850<br>40 | μA<br>mA |

**Notes**

- <sup>(1)</sup> Pulse test: 300 μs pulse width, 1 % duty cycle
- <sup>(2)</sup> Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |            |                  |         |          |          |          |      |
|---|------------|------------------|---------|----------|----------|----------|------|
| PARAMETER   |            | SYMBOL           | VT3060G | VFT3060G | VBT3060G | VIT3060G | UNIT |
| Typical thermal resistance  | per diode  | R <sub>θJC</sub> | 3.2     | 6.2      | 3.2      | 3.2      | °C/W |
|   | per device |                  | 1.9     | 5.0      | 1.9      | 1.9      |      |

| ORDERING INFORMATION (EXAMPLE) |                |                 |              |               |               |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|
| PACKAGE                        | PREFERRED P/N  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-220AB                       | VT3060G-E3/4W  | 1.88            | 4W           | 50/tube       | Tube          |
| ITO-220AB                      | VFT3060G-E3/4W | 1.76            | 4W           | 50/tube       | Tube          |
| TO-263AB                       | VBT3060G-E3/4W | 1.39            | 4W           | 50/tube       | Tube          |
| TO-263AB                       | VBT3060G-E3/8W | 1.39            | 8W           | 800/reel      | Tape and reel |
| TO-262AA                       | VIT3060G-E3/4W | 1.45            | 4W           | 50/tube       | Tube          |

**RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

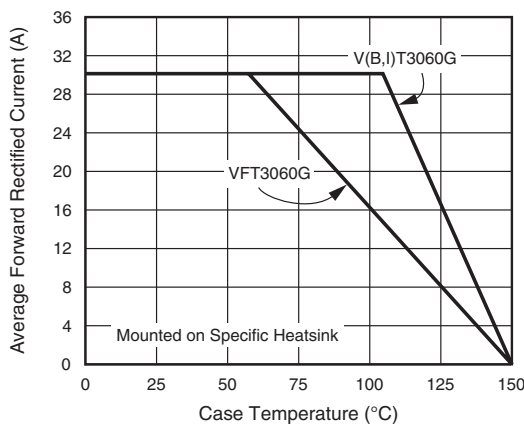


Fig. 1 - Maximum Forward Current Derating Curve

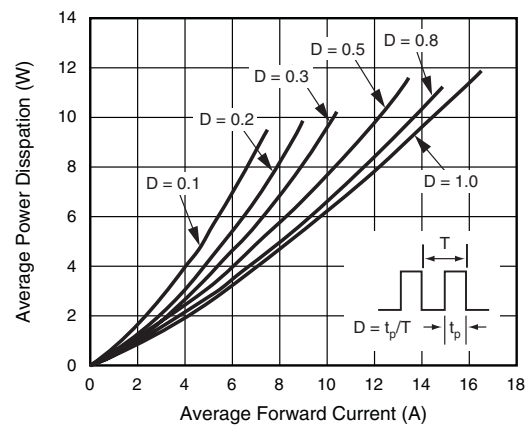


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

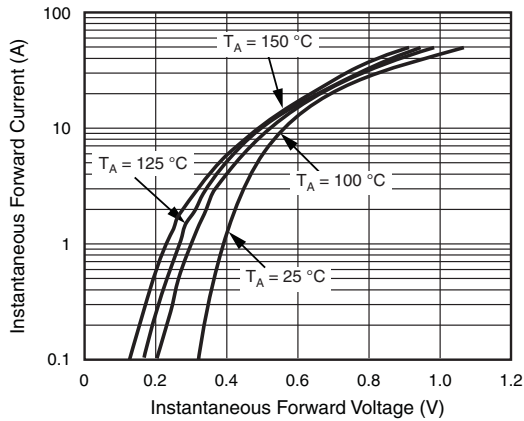


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

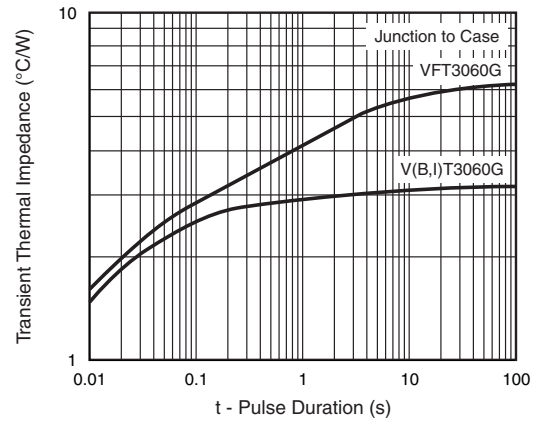


Fig. 5 - Typical Transient Thermal Impedance Per Diode

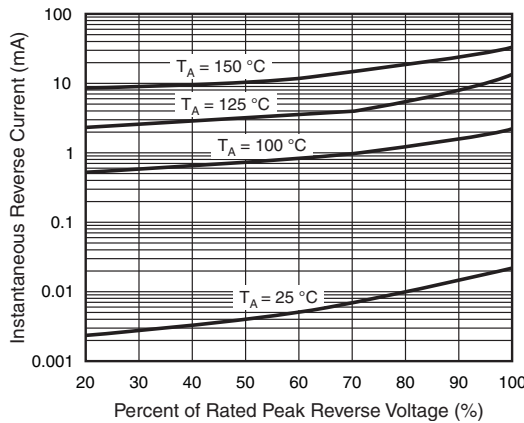


Fig. 4 - Typical Reverse Characteristics Per Diode

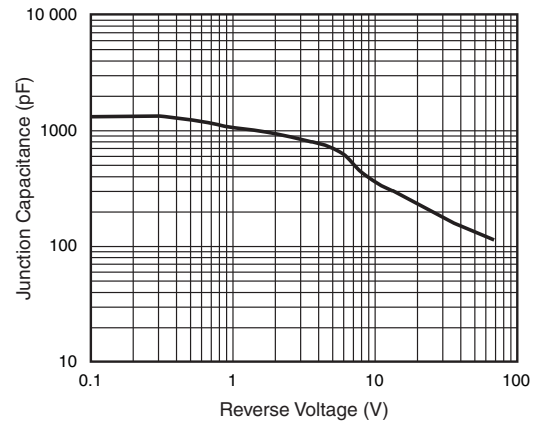
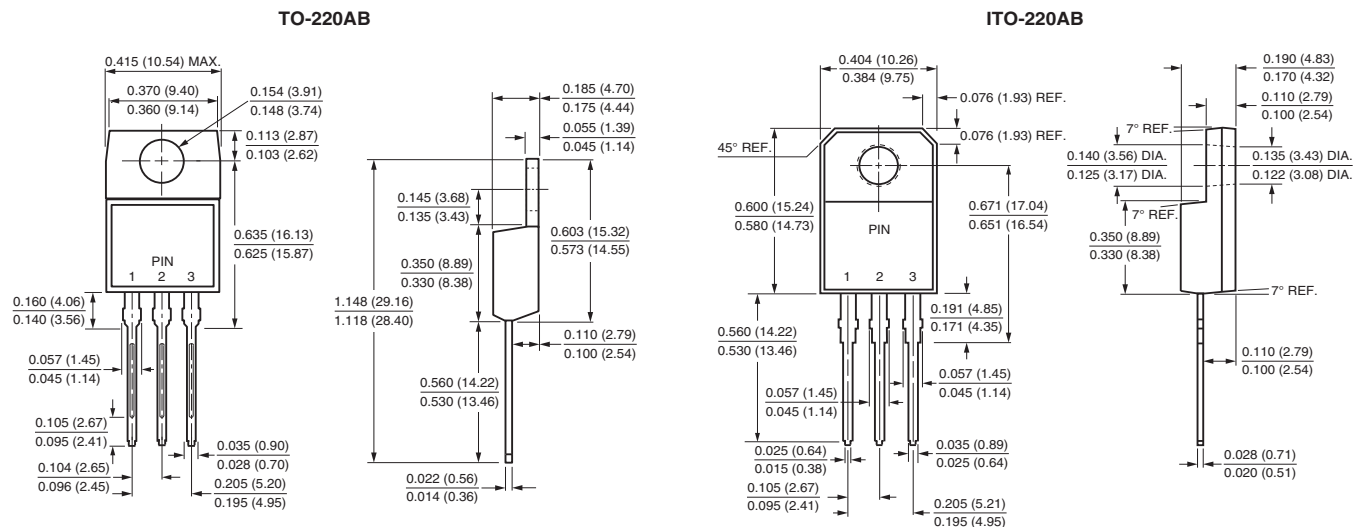


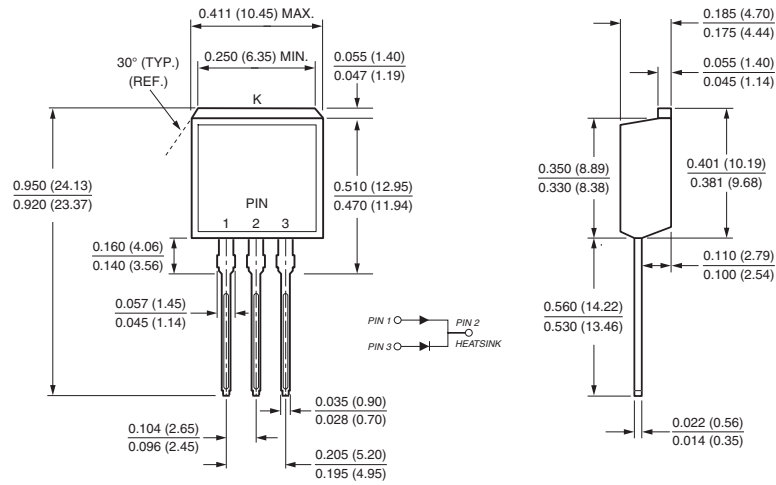
Fig. 6 - Typical Junction Capacitance Per Diode

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

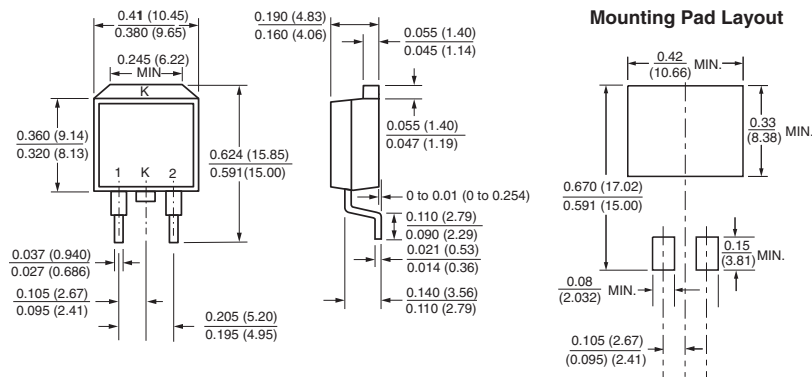




### TO-262AA



### TO-263AB





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